



<b>FORM PTO-1449</b> <b>INFORMATION DISCLOSURE STATEMENT</b>				Attorney ref.: <b>AI 412NP</b>		Application serial No.: <b>10/577,361</b>	
				Applicant(s): <b>Masaru TAKAISHI</b>			
				Filing date: <b>April 28, 2006</b>		Group art unit: <b>2895</b>	
<b>FOREIGN PATENT DOCUMENTS</b>							
Examiner Initial		Document Number	Date	Country	Class	Sub-Class	Translation
	AA	63-58960	03-14-1988	JAPAN			Abstract
	AB	EP 1 168 455 A2	01-02-2002	EUROPE			N/a
<b>OTHER (Including Author, Title, Date, Pertinent Pages, etc.)</b>							
	AC	SAGGIO M ET AL: "MDMESH <sup>TM</sup> : INNOVATIVE TECHNOLOGY FOR HIGH VOLTAGE POWERMOSFETS" PROCEEDINGS OF THE INTERNATIONAL SYMPOSIUM ON POWERSEMICONDUCTOR DEVICES AND ICS, NEW YORK, NY, US, 22 May 2000 (2000-05-22), pages 65-68, XP000985371					
Examiner: /Edward Wojciechowicz/					Date Considered: 09/30/2008		
EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.							